MOS LSI

LC89950



# 1H Delay Line for PAL Systems

### Preliminary

### **Overview**

The LC89950 is an IC that provides 1H delay processing for color difference signals used in PAL and SECAM format TV. The LC89950 has two CCD systems, one for the R-Y and one for the B-Y signal, and drives these CCDs with a 4-MHz clock generated within the IC. It uses a sandcastle-shaped three-value input clock with a 1 H (64  $\mu$ s) period.

### **Features**

- 5-V single-voltage power supply
- Two input and output systems, one each for R-Y and B-Y signals
- Takes a sandcastle pulse (SCP) as the input clock, and converts that to a burst gate pulse (BGP) signal internally.
- Generates the CCD drive pulses (4 MHz) from the input clock using a PLL circuit.
- Uses BGP as clamp pulses and clamps the no signal section (back porch) once every horizontal scan period.
- The output signal is in-phase with the input signal

# **Functions**

- Two on-chip 254.5-bit CCD shift registers
- CCD drive circuits
- Sample-and-hold circuit
- · Burst gate pulse detection circuit
- $256 \times PLL$  circuit

# **Specifications**

#### Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>		-0.3 to +6.0	V
Allowable power dissipation	Pd max		450	mW
Operating temperature	Topr		-10 to +60	°C
Storage temperature	Tstg		-55 to +125	°C

#### Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply voltage	V <sub>DD</sub>		4.75	5.0	5.25	V
Input signal amplitude	V <sub>INPP(R-Y)</sub>			500	700	mV
	V <sub>INPP(B-Y)</sub>			500	700	mV

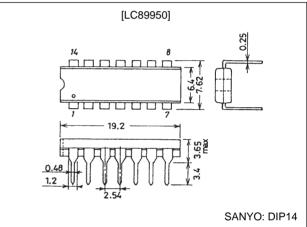
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- Auto-bias and input clamping circuits
- 4-MHz output circuit

# **Package Dimensions**

#### unit: mm

#### 3003A-DIP14



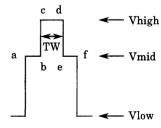
		Switch States								
Parameter	Symbol	SW1	SW2	SW3	SW4	Test conditions	min	typ	max	Unit
Current drain	I <sub>DD</sub>	a/b	а	a/b	a/b	1	5	10	15	mA
Output pin voltage (pin 1)	V <sub>OUT</sub> (R-Y)	b	а	a/b	a/b	2	0.7	1.7	2.7	V
Output pin voltage (pin 3)	V <sub>OUT</sub> (B-Y)	а	а	a/b	a/b	2	0.7	1.7	2.7	V
Input pin voltage (pin 7)	V <sub>IN</sub> (R-Y)	b	а	a/b	a/b	2	1.4	2.4	3.4	V
Input pin voltage (pin 5)	V <sub>IN</sub> (B-Y)	а	а	a/b	a/b	2	1.4	2.4	3.4	V
Voltage gain	G <sub>V</sub> (R-Y)	а	а	а	а	3	-2	0	+2	dB
	G <sub>V</sub> (B-Y)	b	а	а	а	3	-2	0	+2	dB
Differential voltage gain	$\Delta G_V$	a⇔b	а	а	а	3		0.1	0.3	dB
Frequency characteristics	G <sub>f</sub> (R-Y)	а	а	а	а	4	-3	-1		dB
	G <sub>f</sub> (B-Y)	b	а	а	а	4	-3	-1		dB
Positive phase input linearity +L6	+L6 (R-Y)	а	а	а	b	5	57	60	63	%
	+L6 (B-Y)	b	а	а	b	5	57	60	63	%
Inverted input linearity -L6	–L6 (R-Y)	а	а	b	b	5	57	60	63	%
	–L6 (B-Y)	b	а	b	b	5	57	60	63	%
Clock leakage (4 MHz)	Lclk (R-Y)	а	а	а	а	6		7	12	mVrms
	Lclk (B-Y)	b	а	а	а	6		7	12	mVrms
Noise level	No (R-Y)	а	а	а	b	7		1	2	mVrms
	No (B-Y)	b	а	а	b	7		1	2	mVrms
Output impedance	Z <sub>OUT</sub> (R-Y)	а	a⇔b	а	а	8	200	300	400	Ω
	Z <sub>OUT</sub> (B-Y)	b	a⇔b	а	а	8	200	300	400	Ω
Delay time	Td (R-Y)	а	а	а	а	9		63.80		μs
	Td (B-Y)	b	а	а	а	9		63.80		μs

# Electrical Characteristics at Ta = 25°C, $V_{\mbox{DD}}$ = 5.0 V, Fscp = 15.625 kHz

#### Sandcastle Pulse (Input Clock) Conditions

Parameter	Symbol	Conditions	min	typ	max	Unit
Input frequency*1	Fscp		14.625	15.625	16.625	kHz
Input pulse width	TW bgp		3.0	4.0	5.0	μs
High level*2	Vhigh		5.9	6.5	7.5	V
Mid level*3	Vmid		2.5	3.5	4.4	V
Low level	Vlow		-0.3	0	2.5	V

Notes: 1. Indicates the synchronization range for the PLL circuit. The delay time changes with the input frequency.
2. Vhigh is the minimum value between c and d.
3. Vmid is the maximum value between a and b and between e and f.



<Sandcastle Pulse Waveform>

#### **Test Conditions**

- 1. Measure the power-supply current when no input signal is supplied.
- 2. Measure the pin voltages on each pin when no input signal is supplied.
- 3. Let V<sub>OUT</sub> be the OUT pin signal amplitude when a 200-kHz 350-mVp-p sine wave is input.

Then, the voltage gain  $(G_V)$  for each of the R-Y and B-Y I/O systems is given by:

$$G_{V} = 20\log \frac{V_{OUT} [mVp-p]}{350 [mVp-p]} [dB]$$

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The R-Y and B-Y voltage gains ( $\Delta G_V$ ) are:

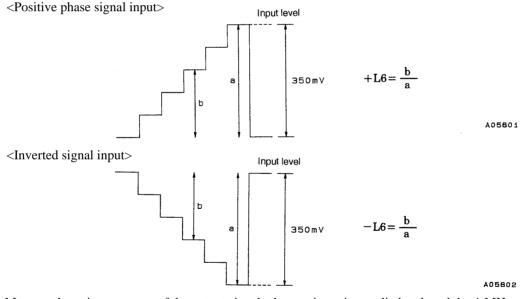
$$\Delta G_{V} = |G_{V}(R-Y) - G_{V}(B-Y)|$$

4. Let V1 be the OUT pin output when a 100-kHz 200-mVp-p sine wave is input.

Let V2 be the OUT pin output when a 1-MHz 200-mVp-p sine wave is input.

$$G_{f} = 20 \log \frac{V2 [mVp-p]}{V1 [mVp-p]} [dB]$$

5. Input a 5-stage step waveform (350 mVp-p) and measure the levels a and b in the output signals. Perform those measurements for both positive phase and inverted signal inputs.



- 6. Measure the noise spectrum of the output signal when no input is supplied and read the 4-MHz peak.
- 7. Pass the output signal through a 2-MHz low-pass filter and a 100-kHz high-pass filter. Then, measure that output with a noise meter, when no input signal is supplied. Use a 2-MHz low-pass filter with an attenuation of -60 dB at 4-MHz.
- 8. Input a 200-kHz 350-mVp-p sine wave.

Let V1 be the OUT pin output when SW2 is set to a.

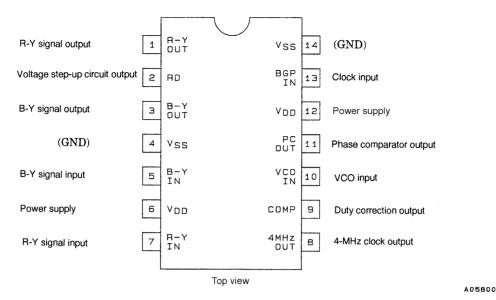
Let V2 be the OUT pin output when SW2 is set to b.

$$Z_{\rm O} = \frac{V1 \ [mVp-p] - V2 \ [mVp-p]}{V2 \ [mVp-p]} \times 500 \ [Ω]$$

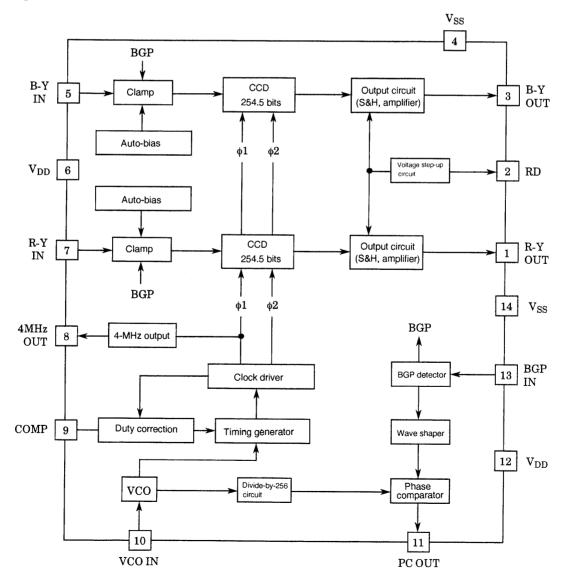
9. Measure the delay time of the OUT pin output with respect to the input signal. When taking this measurement, exclude the delay associated with the low-pass filter.

#### LC89950

#### **Pin Assignment**

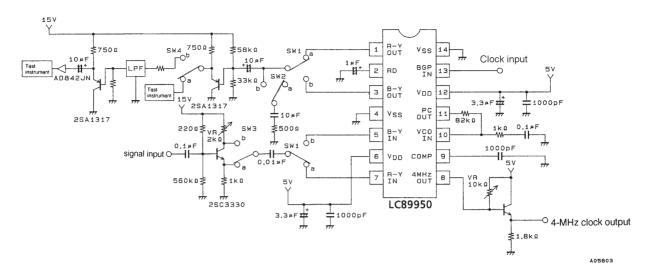


Note: Pins 1 and 3 are referred to collectively as the "OUT pin."



#### **Block Diagram**

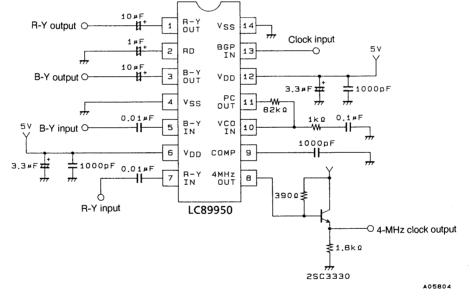
#### **Test Circuit**



Notes: 1. Adjust VR (2 k $\Omega$ ) so that the output amplitudes when SW3 is set to the a and b positions are equal.

- 2. LPF is a 2-MHz low-pass filter. Use a filter with an attenuation of -60 dB at 4 MHz.
- 3. The operational amplifier (AD842JN) is a non-inverting amplifier, and the gain from the SW1 output to the operational amplifier output should be 0 dB.

#### **Sample Application Circuit**



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